

Telecom Performance TCXO / VCTCXO

CONNOR WINFIELD



2111 Comprehensive Drive
Aurora, Illinois 60505
Phone: 630-851-4722
Fax: 630-851-5040
www.conwin.com

US Headquarters:
630-851-4722
European Headquarters:
+353-61-472221

Description:

The Connor-Winfield 5.0x7.0mm Temperature Compensated Crystal Controlled Oscillators and Voltage Controlled Temperature Compensated Crystal Controlled Oscillators are designed for use in S3 Telecom Applications. Through the use of Analog Temperature Compensation, this device is capable of holding sub 1-ppm stabilities over the commercial or the industrial temperature ranges. All models meet +/-4.6 ppm accuracies for twenty years. Three STRATUM 3 compliant model series are available.



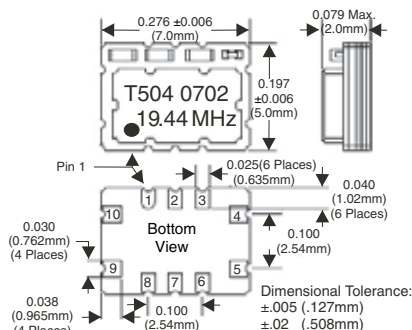
Features

- Miniature 5.0 x 7.0mm Surface Mount Package
- 3.3V Operation
- LVCMOS or Clipped Sinewave Output Logic
- Frequency Stabilities Available:
 - T50x / T60x / T70x: ± 0.28 ppm
 - T51x / T61x / T71x: ± 0.50 ppm
 - T52x / T62x / T72x: 1.00ppm
- Temperature Ranges Available:
 - T5xx Series: 0 to 70°C
 - T6xx Series: -40 to 85°C
 - T7xx Series: -20 to 70°C
- Frequency Tolerance: +/-4.60ppm for 20 yrs.
- Aging: <4.63E-13 / second
- Low Jitter <1pS RMS
- Tri-State Enable/Disable
- Tape and Reel Packaging
- RoHS Compliant / Lead Free
- Recommended for New Designs

STRATUM 3 Applications

- Timing Reference Clocks
- Instrumentation

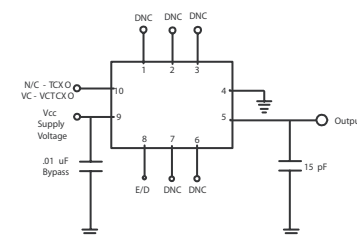
Package Layout



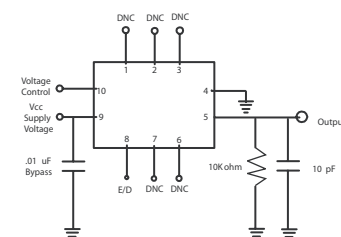
Pin Connections

- 1: Do Not Connect
- 2: Do Not Connect
- 3: Do Not Connect
- 4: Ground
- 5: Output
- 6: Do Not Connect
- 7: Do Not Connect
- 8: Tri-state Enable /Disable
- 9: Supply, Vcc
- 10: Voltage Control (VCTCXO)
N/C (TCXO)

LVCMOS Test Circuit



Clipped Sinewave Test Circuit



Standard Frequencies Available *

6.4 MHz, 9.72 MHz, 10.0 MHz, 10.24 MHz, 12.5 MHz, 12.8 MHz, 13.5 MHz, 19.2 MHz, 19.44 MHz, 20.0 MHz, 20.48 MHz, 25.0 MHz, 27.0 MHz, 38.88 MHz

* Available frequencies from the factory for small quantity orders or quick delivery. Additional frequencies are available.

Ordering Information

Table 1.0

T	5	0	4	019.44M
Type: Precision TCXO VCTCXO 5x7mm	Temperature Range 5 = 0 to 70°C 6 = -40 to 85°C 7 = -20 to 70°C	Frequency Stability 0 = ± 0.28 ppm 1 = ± 0.50 ppm 2 = ± 1.00 ppm	Features 2 = TCXO, LVCMOS, 3.3 Vdc 3 = TCXO, Clipped Sinewave, 3.3 Vdc 4 = VCTCXO, LVCMOS, 3.3 Vdc 5 = VCTCXO, Clipped Sinewave, 3.3 Vdc	Output Frequency Frequency Format -xxx.xM Min. * -xxx.xxxxxM Max. * * Amount of numbers after the decimal point. M = MHz

Example:

T504-019.44M = 5x7mm, VCTCXO, LVCMOS, 3.3Vdc, 0 to 70°C, ± 28 ppm, Output Frequency 19.44MHz

To order an T504 with an output frequency of: 6.4 MHz = T504-006.4M

20 MHz = T504-020.0M

38.88 MHz = T504-038.88M



Bulletin **Tx176**
Page **1 of 4**
Revision **10**
Date **07 Jan 2010**

Absolute Maximum Ratings

Table 2

Parameter	Minimum	Nominal	Maximum	Units	Notes
Storage Temperature	-55	-	125	°C	
Supply Voltage (Vcc)	-0.5	-	6.0	Vdc	
Input Voltage	-0.5	-	Vcc+0.5	Vdc	

Model Specifications

Table 3.0

Model Number	T502	T503	T504	T505	✓ STRATUM 3
Temperature Range		0 to 70°C			
Model Number	T602	T603	T604	T605	✓ STRATUM 3
Temperature Range		-40 to 85°C			
Model Number	T702	T703	T704	T705	✓ STRATUM 3
Temperature Range		-20 to 70°C			
Output Type	LVC MOS	Clipped Sinewave	LVC MOS	Clipped Sinewave	
TCXO / VCTCXO	TCXO	TCXO	VCTCXO	VCTCXO	
Frequency Range		6.4 to 40 MHz			
Frequency Stability		±0.28ppm			1
Supply Voltage		3.3Vdc			
Holdover Stability		±0.32ppm			2
Aging / Life		±3.0ppm			3
Aging / Day		±40ppb			
Aging / Second		4.63E-13			

Model Specifications

Table 4.0

Model Number	T512	T513	T514 T515		
Temperature Range		0 to 70°C			
Model Number	T612	T613	T614	T615	
Temperature Range		-40 to 85°C			
Model Number	T712	T713	T714	T715	
Temperature Range		-20 to 70°C			
Output Type	LVC MOS	Clipped Sinewave	LVC MOS	Clipped Sinewave	
TCXO / VCTCXO	TCXO	TCXO	VCTCXO	VCTCXO	
Frequency Range		6.4 to 40 MHz			
Frequency Stability		±0.50ppm			1
Supply Voltage		3.3Vdc			
Frequency Aging		±3.0ppm			3

Model Specifications

Table 5.0

Model Number	T522	T523	T524	T525	
Temperature Range		0 to 70°C			
Model Number	T622	T623	T624	T625	
Temperature Range		-40 to 85°C			
Model Number	T722	T723	T724	T725	
Temperature Range		-20 to 70°C			
Output Type	LVC MOS	Clipped Sinewave	LVC MOS	Clipped Sinewave	
TCXO / VCTCXO	TCXO	TCXO	VCTCXO	VCTCXO	
Frequency Range		6.4 to 40 MHz			
Frequency Stability		±1.00ppm			1
Supply Voltage		3.3Vdc			
Frequency Aging		±3.0ppm			3

Notes:

- 1) Frequency stability vs. change in temperature. $[\pm(F_{max} - F_{min})/2.F_0]$.
- 2) Inclusive of frequency stability, supply voltage change ($\pm 1\%$), aging, for 24 hours.
- 3) Over twenty years.

Operating Specifications

Table 6.0

Parameter	Minimum	Nominal	Maximum	Units	Notes
TCXO Frequency Calibration @ 25°C	-1.00	-	1.00	ppm	1
Supply Voltage Variation. (Vcc±5%)	-0.05	-	0.05	ppm	
Load Coefficient, ±5%	-0.05	-	0.05	ppm	
Static Temperature Hysteresis	-0.4	-	0.4	ppm	2
Total Frequency Tolerance	-4.60	-	4.60	ppm	3
Supply Voltage (±5%) (Vcc)	3.135	3.3	3.465	Vdc	4
Supply Current (Icc)	-	6	10	mA	
Period Jitter	-	3	5	ps rms	
Integrated Phase Jitter (BW=12kHz to 20MHz)	-	0.3	1.0	ps rms	
SSB Phase Noise at 10Hz offset	-	-90	-85	dBc/Hz	5
SSB Phase Noise at 100Hz offset	-	-120	-115	dBc/Hz	5
SSB Phase Noise at 1KHz offset	-	-140	-135	dBc/Hz	5
SSB Phase Noise at >10KHz offset	-	-150	-145	dBc/Hz	5
SSB Phase Noise at >100KHz offset	-	-152	-157	dBc/Hz	5
Start Up Time	-	-	1	ms	6

Input Characteristics For Enable / Disable Function (Pad 8)

Table 7.0

Parameter	Minimum	Nominal	Maximum	Units	Notes
Enable Voltage (High) or open circuit (Vih)	70% Vcc	-	-	Vdc	7
Disable Voltage (Low) Output Tri-stated (Vil)	-	-	30% Vcc	Vdc	

Input Characteristics For Voltage Control (Pad10)

Table 8.0

Parameter	Minimum	Nominal	Maximum	Units	Notes
Control Voltage Range (Vcc = 3.3V) (Vc)	0.3	1.65	3.0	Vdc	
Frequency Tuning	±10	-	-	ppm	8
Linearity	±5	-	-	%	
Input Impedance	100K	-	-	Ohm	
Slope	Positive				

LVC MOS Output Characteristics

Table 9.0

Parameter	Minimum	Nominal	Maximum	Units	Notes
LOAD	-	15	-	pF	9
Voltage (High) (Voh)	90%Vcc	-	-	Vdc	
(Low) (Vol)	-	-	10%Vcc	Vdc	
Current (High) (Ioh)	-4	-	-	mA	
(Low) (Iol)	-	-	4	mA	
Duty Cycle at 50% of Vcc	45	50	55	%	
Rise / Fall Time 10% to 90%	-	-	8	ns	

Clipped Sinewave Output Characteristics

Table 10.0

Parameter	Minimum	Nominal	Maximum	Units	Notes
Load					10
Output Load Resistance	-	10K	-	Ohms	
Output Load Capacitance	-	0	-	pF	11
Output Voltage (< 40 MHz)	1.00	-	-	V pk-pk	
Output Voltage (> 40 MHz)	0.80	-	-	V pk-pk	

Note

- 1) TCXO: Initial calibration @ 25°C. Specifications at time of shipment after 48 hours of operation.
- 2) Frequency change after reciprocal temperature ramped over the operating range. Frequency measured before and after at 25°C.
- 3) Inclusive of calibration @ 25°C, frequency vs. change in temperature, change in supply voltage (±5%), load change (±5%), reflow soldering process and 20 years aging.
- 4) For best in application performance, careful selection of an external power source is critical. Select an external regulator that meets or exceeds to following specifications regarding voltage regulation tolerance, initial accuracy, temperature coefficient, voltage noise, and low voltage noise density
Factory Test Conditions: Initial Accuracy ±2mv, Noise (0.1Hz to 10 KHz) 15uV p-p, Voltage Noise Density = 50nV/sqrt Hz, Temperature Coefficient < 5ppm°C.
- 5) Phase noise measurements Fo = 20 MHz, other frequencies may vary by 20log F/20MHz.
- 6) Typical start up time for the frequency range of 12.8 MHz to 25 MHz ≤330 us.
- 7) Leave Pad 8 unconnected if enable / disable function is not required. When tri-stated, the output stage is disabled but the oscillator and compensation circuit are still active (current consumption ≤ 1mA).
- 8) Additional pull ranges are available; please contact the factory for additional information.
- 9) For best performance it is recommended that the device connected to this output should have an equivalent input capacitance of 15pF.
- 10) Output is AC coupled.
- 11) For best performance it is recommended that the device connected to this output should have an equivalent input capacitance of 10pF.

